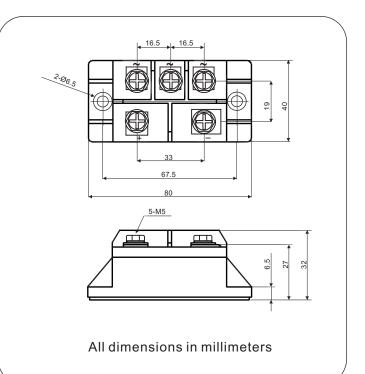


**Nell High Power Products** 

# Three-Phase Bridge Rectifier, 75A

MTP7508S Thru MTP7518S (MTP75/08 Thru MTP75/18)





## FEATURES

- UL recognition file number E320098
- Typical IR less than 2.0 µA
- High surge current capability
- Low thermal resistance
- Compliant to RoHS
- Isolation voltage up to 2500V

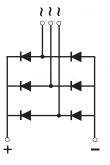
## **TYPICAL APPLICATIONS**

General purpose use in AC/DC bridge full wave rectification for big power supply, field supply for DC motor, industrial automation applications.

## ADVANTAGE

- International standard package Epoxy meets UL 94 V-O flammability rating
- Small volume, light weight
- Small thermal resistance
- Weight: 183g (6.5 ozs)





PRIMARY CHARACTERRISTICS						
I <sub>F(AV)</sub>	75A					
V <sub>RRM</sub>	800V to 1800V					
I <sub>FSM</sub>	1000A					
I <sub>R</sub>	20 µA					
V <sub>F</sub>	1.3V					
T <sub>J max.</sub>	150°C					



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MAJOR RATINGS AND CHARACTERISTICS (T <sub>A</sub> = 25°C unless otherwise noted)									
PARAMETER	SYMBOL	MTP75S							
		08	10	12	16	18	UNIT		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	800	1000	1200	1600	1800	V		
Peak reverse non-repetitive voltage	V <sub>RSM</sub>	900	1100	1300	1700	1900	V		
Maximum DC blocking voltage	V <sub>DC</sub>	800	1000	1200	1600	1800	V		
Maximum average forward rectified output current	I <sub>F(AV)</sub>	75					А		
Peak forward surge current single sine-wave superimposed on rated load	I <sub>FSM</sub>	1000					A		
Rating (non-repetitive, for t greater than 1 ms and less than 8.3 ms) for fusing	l <sup>2</sup> t	5100				A <sup>2</sup> s			
RMS isolation voltage from case to leads	V <sub>ISO</sub>	2500			V				
Operating junction storage temperature range	TJ	-40 to 150				°C			
Storage temperature range	T <sub>STG</sub>	-40 to 125					°C		

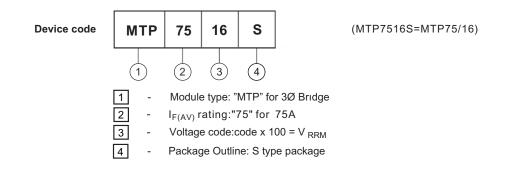
ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25°C unless otherwise noted)									
PARAMETER	TEST CONDITIONS	SYMBOL	MTP75S						
PARAMETER		STNIBUL	08	10	12	16	18	UNIT	
Maximum instantaneous forward drop per diode	I <sub>F</sub> = 75A	V <sub>F</sub>	1.3					V	
Maximum reverse DC current at rated DC blocking	T <sub>A</sub> = 25°C	la.	20				μA		
voltage per diod	T <sub>A</sub> = 150°C	IR			4000			μΑ	

<b>THERMAL AND MECHANICAC</b> (T <sub>A</sub> = 25°C unless otherwise noted)									
PARAMETER TEST CONDITIONS	SYMBOL	MTP75S							
	STWIDUL	08	10	12	16	18	UNIT		
Typical thermal resistance junction to case	Single-side heat dissipation, sine half wave	$R_{\theta JC}^{(1)}$			0.24			°C/W	
Mounting torque ± 10 %to heatsink M6 to terminal M5A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound.				4			Nm		
		4					NIII		
Approximate weight					183			g	

Notes

(1) With heatsink, single side heat dissipation, half sine wave.

(2) M6 screw.





# MTP75S Series R

# **Nell High Power Products**

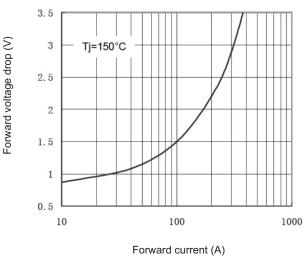
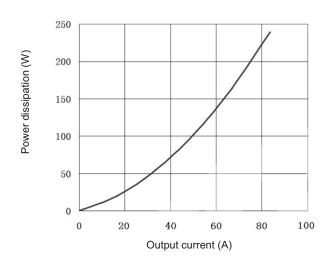
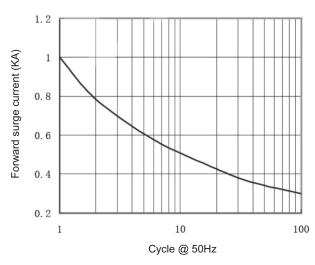


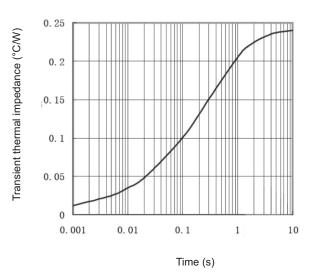
Fig.1 Forward characteristic

## Fig.3 Power dissipation vs. output current









## Fig.2 Thermal Impedance (junction to case)



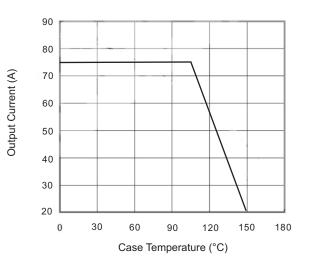


Fig.6 l<sup>2</sup>t characteristic

